

HD74LVC138

3-to-8-line Decoder / Demultiplexer

REJ03D0349-0300Z (Previous ADE-205-068B (Z)) Rev.3.00 Jul. 23, 2004

Description

The HD74LVC138 has three binary select inputs in a 16 pin package. If the device is enabled these inputs determine which one of the eight normally high outputs will go low. Two active low and one active high enables are provided to ease the cascading of decoders. Low voltage and high-speed operation is suitable at the battery drive product (note type personal computer) and low power consumption extends the life of a battery for long time operation.

Features

- $V_{CC} = 2.0 \text{ V to } 5.5 \text{ V}$
- All inputs V_{IH} (Max.) = 5.5 V (@ V_{CC} = 0 V to 5.5 V)
- Typical V_{OL} ground bounce < 0.8 V (@ V_{CC} = 3.3 V, Ta = 25°C)
- Typical V_{OH} undershoot > 2.0 V (@ V_{CC} = 3.3 V, Ta = 25°C)
- High output current ± 24 mA (@V_{CC} = 3.0 V to 5.5 V)
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LVC138FPEL	SOP-16 pin (JEITA)	FP-16DAV	FP	EL (2,000 pcs/reel)
HD74LVC138TELL	TSSOP-16 pin	TTP-16DAV	Т	ELL (2,000 pcs/reel)

Note: Please consult the sales office for the above package availability.

Function Table

Inputs

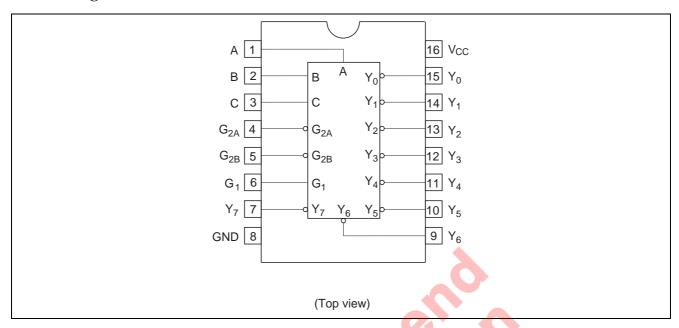
Enab	le		Selec	ct		Outp	uts						
G ₁	G_{2A}	G_{2B}	С	В	Α	Y ₀	Y ₁	Y ₂	Y ₃	Y ₄	Y ₅	Y ₆	Y ₇
X	Х	Н	Χ	X	X	Н	Н	Н	Н	Н	Н	Н	Н
X	Н	Χ	Χ	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н
L	Х	Χ	Χ	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н
Н	L	L	L	L	L	L	Н	Н	Н	Н	Н	Н	Н
Н	L	L	L	L	Н	Н	L	Н	Н	Н	Н	Н	Н
Н	L	L	L	Н	L	Н	Н	L	Н	Н	Н	Н	Н
Н	L	L	L	Н	Н	Н	Н	Н	L	Н	Н	Н	Н
Н	L	L	Н	L	L	Н	Н	Н	Н	L	Н	Н	Н
Н	L	L	Н	L	Н	Н	Н	Н	Н	Н	L	Н	Н
Н	L	L	Н	Н	L	Н	Н	Н	Н	Н	Н	L	Н
Н	L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	L

H: High level

L: Low level

X: Immaterial

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V _{CC}	-0.5 to 6.0	V	
Input diode current	I _{IK}	-50	mA	$V_{I} = -0.5 \text{ V}$
Input voltage	VI	-0.5 to 6.0	V	
Output diode current	l _{ok}	-50	mA	$V_{O} = -0.5 \text{ V}$
		50		$V_O = V_{CC} + 0.5 \text{ V}$
Output voltage	Vo	-0.5 to V_{CC} +0.5	V	
Output current	lo	±50	mA	
V _{CC} , GND current / pin	I _{CC} or I _{GND}	100	mA	
Storage temperature	Tstg	-65 to +150	°C	

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V _{CC}	1.5 to 5.5	V	Data retention
		2.0 to 5.5		At operation
Input / output voltage	Vı	0 to 5.5	V	G, A, B, C
	Vo	0 to V _{CC}	V	Y_0 to Y_7
Operating temperature	Та	-40 to 85	°C	
Output current	I _{OH}	-12	mA	V _{CC} = 2.7 V
		-24 ^{*2}		$V_{CC} = 3.0 \text{ V to } 5.5 \text{ V}$
	I _{OL}	12	mA	V _{CC} = 2.7 V
		24 ^{*2}		V _{CC} = 3.0 V to 5.5 V
Input rise / fall time *1	t _r , t _f	10	ns/V	

Notes: 1. This item guarantees maximum limit when one input switches.

Waveform: Refer to test circuit of switching characteristics.

2. Duty cycle $\leq 50\%$

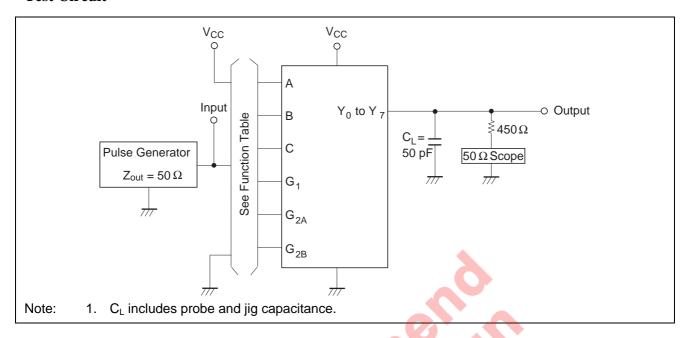
Electrical Characteristics

			Ta = -4	0 to 85°C		
Item	Symbol	V _{CC} (V)	Min	Max	Unit	Test Conditions
Input voltage	V_{IH}	2.7 to 3.6	2.0	_	V	
		4.5 to 5.5	V _{CC} ×0.7	_		
	V _{IL}	2.7 to 3.6	-	0.8	V	
		4.5 to 5.5	-0)	V _{CC} ×0.3		
Output voltage	V_{OH}	2.7 to 5.5	V _{CC} -0.2	- 0	V	$I_{OH} = -100 \mu A$
		2.7	2.2	_	_	$I_{OH} = -12 \text{ mA}$
		3.0	2.4	7	_	
		3.0	2.0	_	_	$I_{OH} = -24 \text{ mA}$
		4.5	3.8	_	_	
	V _{OL}	2.7 to 5.5	6-7	0.2	V	$I_{OL} = 100 \mu A$
		2.7		0.4	_	I _{OL} = 12 mA
		3.0	_	0.55	_	I _{OL} = 24 mA
	1	4.5	_	0.55	_	
Input current	I _{IN}	0 to 5.5	_	±5.0	μA	V _{IN} = 5.5 V or GND
Quiescent supply current	Icc	5.5		20	μA	V _{IN} = V _{CC} or GND
	ΔI_{CC}	3.0 to 3.6	_	500	μΑ	V_{IN} = one input at(V_{CC} –0.6)V, other inputs at V_{CC} or GND

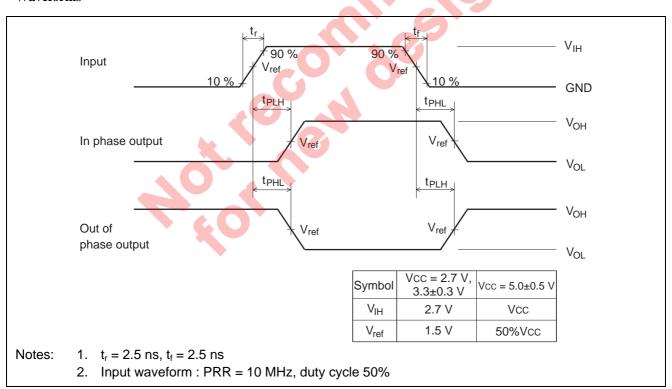
Switching Characteristics

			$Ta = -40 \text{ to } 85^{\circ}C$				From	То
Item	Symbol	V _{CC} (V)	Min	Тур	Max	Unit	(Input)	(Output)
Propagation delay time	t _{PLH}	2.7	_	7.0	10.0	ns	G, A, B, C	Y ₀ to Y ₇
	t _{PHL}	3.3±0.3	1.5	5.0	9.0			
		5.0±0.5	_	3.5	7.5			
Input capacitance	C _{IN}	2.7	_	3.0	_	pF		
Output capacitance	Co	2.7	_	15.0	_	pF		

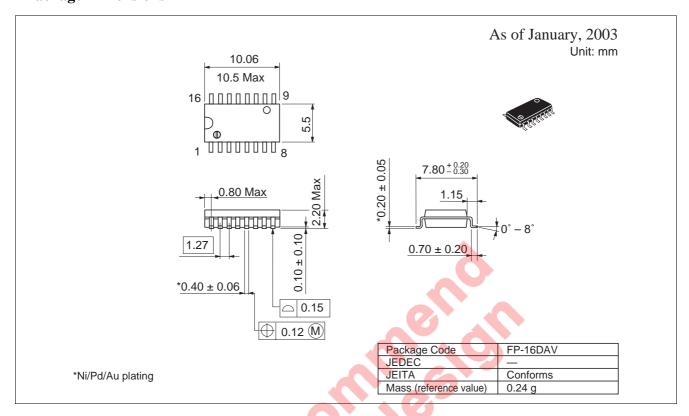
Test Circuit

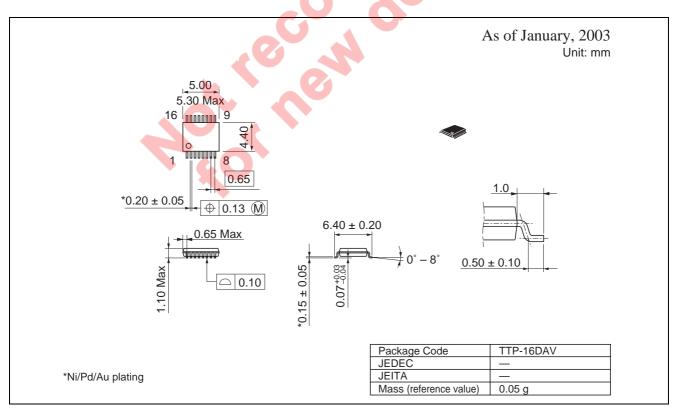


Waveforms



Package Dimensions





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